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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

**OHTAKE, Fumio et al.**

Serial No.: 09/749,590

Filed: December 28, 2000

For: **SEMICONDUCTOR DEVICE HAVING GATE ELECTRODES WITH POLYMETAL  
STRUCTURE OF POLYCRYSTALLINE SILICON FILMS AND METAL FILMS** (as  
amended)

Group Art Unit 2814

Examiner: MAI, Anh D.

P.T.O. Confirmation No.: 2831

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OCT 14 2002  
TECHNOLOGY CENTER 2800  
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**AMENDMENT**

Commissioner for Patents  
Washington, D.C. 20231

October 2, 2002

Sir:

In response to the Office Action dated June 6, 2002, please amend the above-identified application  
as follows:

**IN THE DRAWINGS:**

Submitted herewith is a Request for Approval of Drawing Corrections, along with proposed  
drawing corrections to Figures 5, 6, 7, 8, 9 and 11, marked in red ink.

**IN THE TITLE:**

Amend the title of the invention, in its entirety, to read as follows:

SEMICONDUCTOR DEVICE HAVING ~~GATE~~ ELECTRODES WITH POLYMETAL  
STRUCTURE OF POLYCRYSTALLINE SILICON FILMS AND METAL FILMS